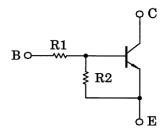
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process) (Bias Resistor built-in Transistor)

RN1707, RN1708, RN1709

Switching, Inverter Circuit, Interface Circuit and Driver Circuit

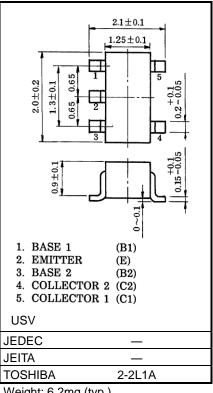
- Including two devices in USV (ultra super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design •
- Reduce a quantity of parts and manufacturing process and miniaturize equipment.
- Various resistance values are available to suit various circuit designs.
- Complementary to RN2707 to RN2709

Equivalent Circuit and Bias Resistor Values



Part No.	R1 (kΩ)	R2 (kΩ)		
RN1707	10	47		
RN1708	22	47		
RN1709	47	22		

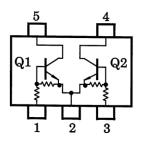
Unit: mm



Weight: 6.2mg (typ.)

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Equivalent Circuit(Top View)



Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit		
Collector-base voltage	RN1707 to 1709	V _{CBO}	50	V	
Collector-emitter voltage	KN1707 to 1709	VCEO	50	V	
	RN1707		6		
Emitter-base voltage	RN1708	V _{EBO}	7	V	
	RN1709		15		
Collector current		lc	100	mA	
Collector power dissipation	RN1707 to 1709	PC*	200	mW	
Junction temperature		Tj	150	°C	
Storage temperature range	e temperature range		−55 to150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

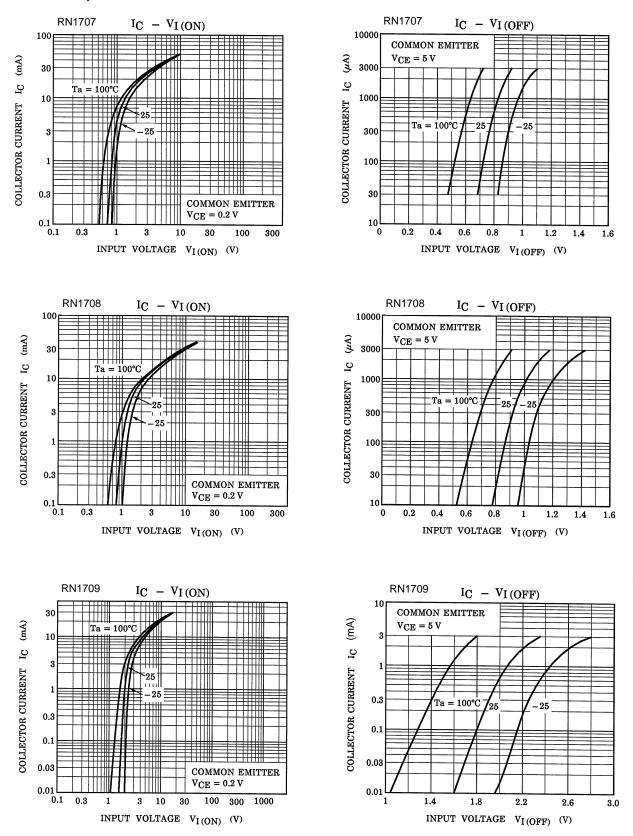
*: Total rating

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1707 to 1709	I _{CBO}	—	$V_{CB} = 50 \text{ V}, \text{ I}_{E} = 0 \text{ mA}$	_	—	100	nA
Collector cut-on cutrent	RN1707 to 1709	ICEO	—	$V_{CE} = 50 \text{ V}, \text{ I}_{B} = 0 \text{ mA}$	_	—	500	nA
	RN1707		—	$V_{EB} = 6 V$, $I_C = 0 mA$	0.081	—	0.15	
Emitter cut-off current	RN1708	IEBO	—	$V_{EB} = 7 V$, $I_C = 0 mA$	0.078	_	0.145	mA
	RN1709		—	V _{EB} = 15 V, I _C = 0 mA	0.167	_	0.311	
	RN1707	hFE	—	V _{CE} = 5 V, I _C = 10 mA	80	—	—	
DC current gain	RN1708		—		80	_	_	
	RN1709		—		70	_	_	
Collector-emitter saturation voltage	RN1707 to 1709	V _{CE (sat)}	_	I _C = 5 mA, I _B = 0.25 mA	_	0.1	0.3	V
	RN1707	VI (ON)	_	V _{CE} = 0.2 V, I _C = 5 mA	0.7	_	1.8	V
Input voltage (ON)	RN1708		_		1.0	_	2.6	
	RN1709		_		2.2	_	5.8	
	RN1707	VI (OFF)	_	VCE = 5 V, IC = 0.1 mA	0.5	_	1.0	V
Input voltage (OFF)	RN1708		_		0.6	_	1.16	
	RN1709		—		1.5	_	2.6	
Transition frequency	RN1707 to 1709	fΤ	—	Vce = 10 V, Ic = 5 mA	_	250	—	MHz
Collector output capacitance	RN1707 to 1709	Cob	_	V _{CB} = 10 V, I _E = 0 mA, f = 1 MHz	-	3	6	pF
	RN1707	RN1707 RN1708 R1 RN1709	_		7	10	13	kΩ
Input resistance	RN1708		_		15.4	22	28.6	
	RN1709				32.9	47	61.1	
	RN1707	R1/R2	—		0.191	0.213	0.232	
Resistance ratio	RN1708		—		0.421	0.468	0.515	
	RN1709		_		1.92	2.14	2.35	

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(Q1, Q2 Common)

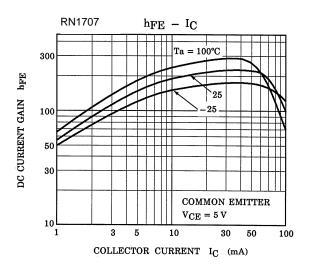


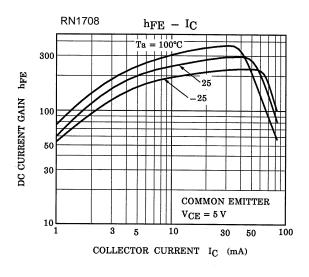
The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

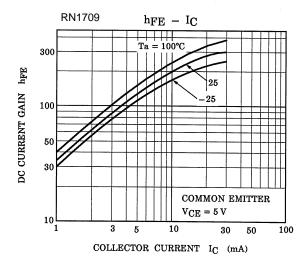
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RN1707 to RN1709

(Q1, Q2 Common)







The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Marking

Part No.	Marking
RN1707	Part No.(abbreviation code)
RN1708	Part No.(abbreviation code)
RN1709	Part No.(abbreviation code)

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